

## WLD-30-505 Green Laser Diode

**505 nm, 30 mW**

### Features

- Good FFP performance
- Higher power
- High efficiency

### Applications

- Excitation
- Bioanalytical
- Photolithography, Curing and others

### Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	P <sub>o</sub>	CW	35	mW
Reverse voltage (LD)	V <sub>RL</sub>	-	2	V
Case temperature	T <sub>c</sub>	-	-10 to +60	°C
Storage temperature	T <sub>s</sub>	-	-40 to +85	°C
Soldering temperature	T <sub>sld</sub>	-	350	°C

### Electrical and Optical Characteristics

Parameter	Symbol	Min	Typ.	Max	Unit	Condition
Threshold current	I <sub>th</sub>	-	30	50	mA	-
Operating current	I <sub>op</sub>	-	75	100	mA	P <sub>o</sub> =30 mW
Operating voltage	V <sub>op</sub>	-	6	7.5	V	
Peak wavelength	λ	497	505	515	nm	
Parallel divergence angle	θ <sub>  </sub>	6	8	10	°	
Perpendicular divergence angle	θ <sub>⊥</sub>	20	23	26	°	
Parallel FFP deviation angle	Δθ <sub>  </sub>	-3	0	3	°	$\frac{20\text{mW}}{I(30\text{mW}) - I(10\text{mW})}$
Perpendicular FFP deviation angle	Δθ <sub>⊥</sub>	-3	0	3	°	
Differential efficiency	η	0.45	0.65	-	mW/mA	



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